

ANGI059064-P49

C-band matched GaN Device

Features:

Frequency: $5.9 \sim 6.4$ GHz Saturated Output Power: $P_{sat} \ge 49$ dBm PowerGain: Gain ≥ 9 dB Add-Efficiency: PAE $\ge 40\%$ Port Matching: $Z_{in}/Z_{out} = 50\Omega$

Description:

ANGI059064-P49 is an internal matching GaN device, which adopts advanced co-planar internal matching MCM and thin film circuit technology. The typical working frequency range is 5.9~6.4GHz. This device can be used in different RF/Microwave system and subsystem.

The high output power level, high efficiency and wide operating temperature range can make application very flexible.

Maximun Ratings (TC=25°C, Not recommended working under this condition):

| | Symbol | Value | Unit |
|--------------------------------------|-----------------|-------------|------|
| Voltage between source and drain | Vds | 40 | V |
| Voltage between gate and source | V _{GS} | -5 | V |
| Storage Temperature Range | Tstg | -65 to +175 | °C |
| Drain and Source Channel Temperature | Tch | 175 | °C |

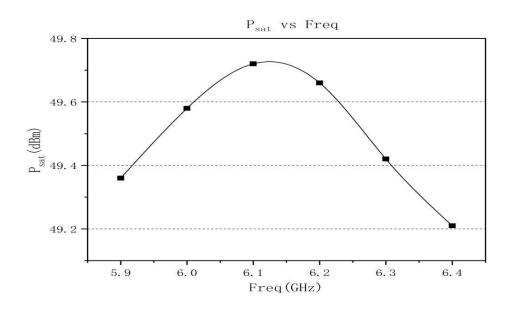
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Electrical Characteristics:

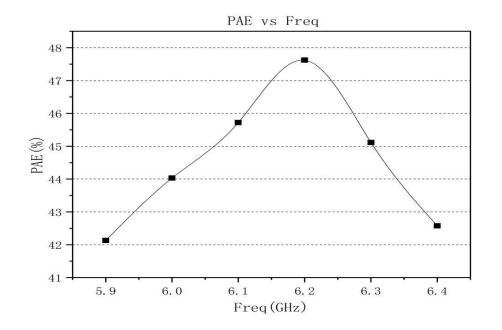
| | | Va | | | | |
|------------------------|--------|---|------|-----|------|------|
| | Symbol | Test condition | Min | Тур | Max | Unit |
| Drain Current | ldsr | Vds=28V CW. Pin: 40dBm Freq: 5.9~6.4GHz | - | 6.2 | - | А |
| Saturated Output Power | Psat | | 49 | - | - | dBm |
| Gain | Gp | | 9 | - | - | dB |
| Add-Efficiency | PAE | | 40 | - | - | % |
| Gain Flatness | ΔG | | -0.8 | - | +0.8 | dB |

Typical Curve:

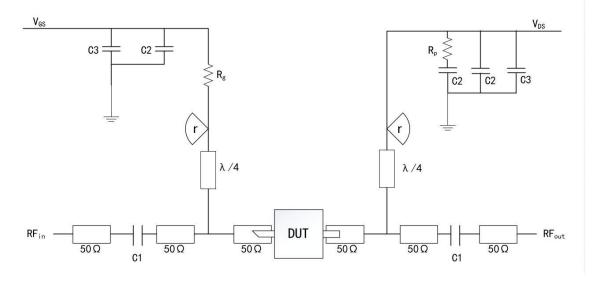


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Application Circuit:



DUT: Device to be tested

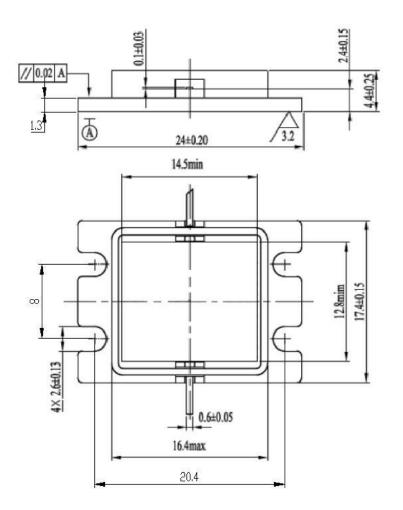
| C1:4.7pF | R _p :51Ω |
|-----------|------------------------------------|
| C2:1000pF | R _G :15Ω |
| C3:100uF | r(radius)≈5.8mm(Rogers5880, 20mil) |



ESD Level:



Outline:



Precautions for use:

- Pay attention to drying transportation and storage.
- Pay attention to anti-static during chip use and assembly, and wear grounding anti-static bracelet.
- When powering up, first apply grid power then add leakage.

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